

Section A

(B) spherical surface. (f) planet. (g) surface

$$(D) 1.6 \times 10^{-18} \text{ J}$$

$$U_2 = -mB \frac{1}{r_2}$$

$$(E) 0.24 \text{ mT K}$$

$$mB(1 - 0.7) \times 10^3$$

(F) remain stationary

$$15 \times 10^{-3} \times \frac{1}{n^2} \sin \theta = 10^3$$

$$\sin \theta = \frac{3}{5}$$

$$(G) 0.3 \text{ mB}$$

$$0.304 \text{ m} \times 10^{-3}$$

$$10^{-7} \text{ idl sin } \theta$$

$$(H) 15 \text{ V}$$

$$m_0 n^2 L A -$$

$$m_0 \frac{N^2}{L^2} \cdot L A -$$

$$10^{-7} (5)(2 \times 10^{-3}) + \frac{3}{5}$$

$$m_0 N^2 \cdot A -$$

$$10^{-9} \times \frac{1}{n^2}$$

$$\frac{1}{2} m v^2 = \frac{kq}{r^2} \cdot \frac{2k}{\sqrt{2}}$$

$$2k^2 \cdot \frac{1}{r^2}$$

$$10^{-9} \times \frac{1}{n^2} \times \frac{2k^2}{r^2}$$

$$10^{-9} \times \frac{1}{n^2} \times \frac{2k^2}{r^2}$$

(I) (B) gamma ray

$$\frac{n_p}{n_e} = \frac{1 + \eta}{1 + 2} = 2 \cdot \frac{\eta}{3} = 0.2m \text{ nT}$$

k_{max}

$$\text{P) } \frac{1}{\sqrt{n}}$$

(B) decreases by 87.5 %.

(C) 0.05 eV

(D) A is false, R is also false

(E) A is true, R is false.

(F)

wrong explanation of A.

(G) Both A and R are correct and R is the
correct explanation of A.

$$\text{Ans} = \frac{mv^2}{r} = qVB$$

$$\text{Period} = \frac{2\pi R}{v} = \frac{mv}{qB} = n$$

$$n = \frac{p}{qB}$$

$$\frac{mv}{qB} = n^2$$

$$mv = n^2 qB$$

$$P_t = 8 \cdot \frac{mv^2}{qB}$$

$$P_t = \frac{mv^2}{qB}$$

$$\text{Ans} = T \left(\frac{mv}{qB} \right)$$

$$T =$$

$$= \frac{qB}{m} \times 100$$

$$= \frac{8 \times 10^{-5}}{2} \times 100$$

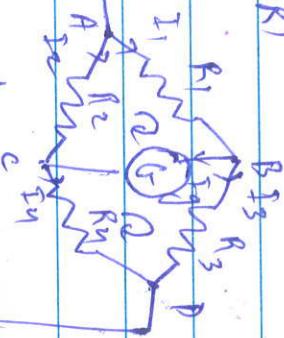
Q. 1-5)

Solution B

(under)

17(b)

Given, $I_g > 0$.



Applying Kirchhoff's loop rule at

Junction B

$$I_1 + I_g = I_3 \quad (\because I_g > 0) \quad \text{--- (i)}$$

Junction C

$$I_2 + I_g = I_1$$

$$\text{a) } I_2 = I_1 \quad (\because I_g > 0) \quad \text{--- (ii)}$$

Applying Kirchhoff's loop rule on loop ABCA

$$-I_1 R_1 + I_2 R_2 + 0 = 0$$

$$\Rightarrow I_2 R_2 - I_1 R_1 = 0 \quad \text{--- (iii)}$$

$$\text{a) } \frac{I_2}{I_1} = \frac{R_1}{R_2} \quad \text{--- (iv)}$$

Applying Kirchhoff's loop rule to BDCB

$$-I_3 R_3 + I_R R_4 + 0 > 0$$

$$\Rightarrow I_R R_4 = I_3 R_3$$

$$\Rightarrow \frac{I_R}{I_3} = \frac{R_3}{R_4}$$

Since $I_2 = I_R$

~~$$I_1 = I_3$$~~

$$\therefore \frac{I_2}{I_1} = \frac{I_R}{I_3}$$

$$\text{Or } \frac{R_1}{R_2} = \frac{R_3}{R_4}$$

which is the balanced Wheatstone bridge condition.

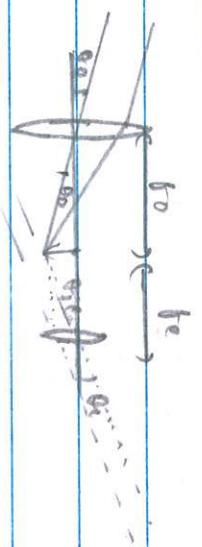
Thus, when resistances in a Wheatstone bridge are in proportion ($\frac{R_1}{R_2} = \frac{R_3}{R_4}$) no current flows through the central galvanometer.

(P.T.O)

(B) In normal adjustment,
magnification of a telescope,

$$m = \frac{f_o}{f_e}$$

$f_o \rightarrow$ focal length of objective
 $f_e \rightarrow$ focal length of eye piece



$$\left(m = \frac{f_o}{f_e} = \frac{f_o}{L} \right)$$

Clearly, separation between lenses, $L = f_o + f_e$.

Given,
 $m = 25$

$$L = 150 \text{ mm}$$

$$f_{le} \quad m f_{le} = f_o$$

$$\Rightarrow u f_{le} = f_o.$$

Ans:

$$f_o + f_{le} = 150$$

$$\Rightarrow f_o + f_{le} = 150$$

$$25 f_{le} = 150$$

$$\Rightarrow f_{le} = 6 \text{ cm}$$

$$\textcircled{b} \quad - \quad f_o = 2u f_{le} = 2 \times 6 = 12 \text{ cm.}$$

Ans \rightarrow Objective focal length $= 12 \text{ cm}$

- (1a) (a) A simple microscope allows, in essence, an object to be brought closer to the eye than the near-point. Thus, it offers magnification.

h \nearrow f_o \searrow In normal adjustment,

$\theta_o \rightarrow$ maximum angle subtended by the object.

\rightarrow

$\frac{h}{D}$

$$\theta_i = \frac{h}{D} \quad ; \quad m = \frac{\theta_i}{\theta_o} = \frac{D}{h}$$

When image is formed at near point:



$$m = \frac{V}{U} \quad V \rightarrow -D \quad (D = 25\text{ cm}).$$

or

Now,

$$\frac{1}{V} - \frac{1}{U} = \frac{1}{f}$$

$$\text{or } \frac{1}{V} - \frac{1}{f} = \frac{1}{U}.$$

$$\therefore m > V \left(\frac{1}{V} - \frac{1}{f} \right)$$

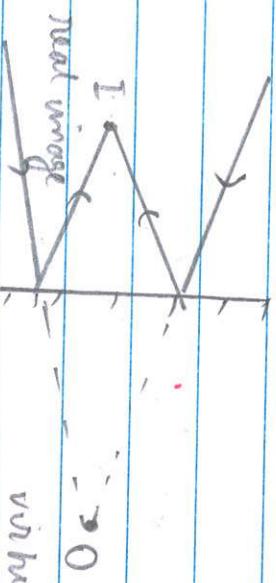
$$\Rightarrow -D \left(\frac{1}{D} - \frac{1}{f} \right)$$

$$\Rightarrow 1 + \frac{D}{f}$$

Thus, in near point adjustment, the microscope offers linear magnification also, so image is magnified even if angular sizes are same.

- (a) (b) Plane and convex mirrors can form real images of virtual objects

as shown.



for converg lens, $f > v$.

$$\frac{1}{v} + \frac{1}{u} = \frac{1}{f}$$

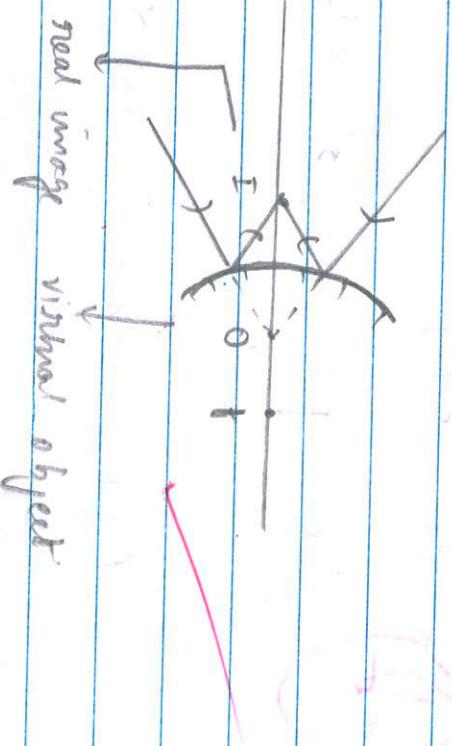
$$\Rightarrow \frac{1}{v} = \frac{1}{f} - \frac{1}{u}$$

$$= \frac{u-f}{fu}$$

$$\Rightarrow v = \frac{fu}{u-f}$$

$\therefore v < 0$ when $u > 0$ and $f < 0$.

(Real image is formed by virtual object).



(20)

Intensity of light = 0.1 NW m^{-2} .
 Area of pupil A = 0.4 cm^2 .

$$\text{Power, } P = I \times A \Rightarrow 0.1 \times 0.4 \times 0.1 \times 10^{-9} \times 0.4 \times 10^{-4} \\ = 4 \times 10^{-15} \text{ W.}$$

Avg wavelength $\lambda = 500 \times 10^{-9} \text{ m} = 5 \times 10^{-7} \text{ m.}$

$$\text{Energy per photon} = \frac{hc}{\lambda} \text{ (energy)}$$

\therefore No. of photons entering pupil per second:

$$n \frac{hc}{\lambda} = 4 \times 10^{-15}$$

$$\Rightarrow n = \frac{4 \times 10^{-15} \times \pi}{c \times h}$$

 Θ

$$= n \times 10^{-15} \times 5 \times 10^{-7}$$

$$\frac{3 \times 10^8 \times 6^{6.6} \times 10^{-34}}{3.3}$$

$\approx 10^{-30} + 3.4$

$$= 10^{-30} \times 10^{-30} + 3.4$$

9.9

$$= \frac{10}{9.9} \times 10^4$$

Expln

$$= 1.01 \times 10^4$$

-:

1.01 $\times 10^4$ photons enter a pupil per second (for minimum intensity)

intensity

n_e → number of electron.

n_n → number of neutrons.

(u)

mini alge, $n_e = n_n = n_i = 1.5 \times 10^{16}$.

$$\text{No. of Si atoms} \rightarrow 5 \times 10^{28} \text{ m}^{-3}$$

Conc. of boron $\rightarrow 1 \text{ ppm}$

$$\text{No. of boron atoms} \rightarrow 5 \times 10^{28} \times 10^{-6} = 5 \times 10^{22} \text{ m}^{-3}$$

xx 1.01

99/100

49

100

ac

We assume ~~that~~ ~~there~~ free holes are due to dopant atoms only

$$n_h = 5 \times 10^{22}$$

For a doped crystal,

$$n_e n_h = n_i^2$$

$$\Rightarrow n_e (5 \times 10^{22}) = 1.5 \times 1.5 \times 10^{32}$$

$$\Rightarrow n_e = \cancel{1.5} \times 1.5 \times 10^{10}$$

5.

$$= 0.45 \times 10^{10}$$

\therefore conc' of holes = $5 \times 10^{22} \text{ m}^{-3}$
conc' of electrons = $0.45 \times 10^{10} \text{ m}^{-3}$

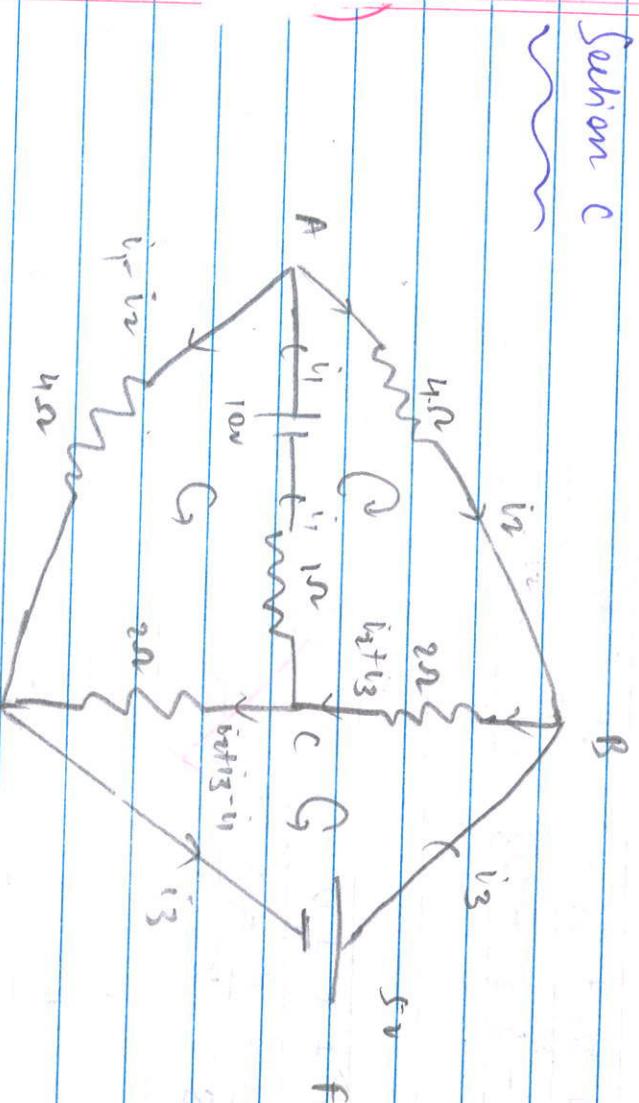
Doping with bivalent boron creates an n -type crystal
($n_h > n_e$)

$$(P - P_0)$$

Solution C

W

(2)



P

The currents we labelled are shown according to Kirchhoff's junction rule.

Applying loop rule to ABCA:

$$10 - u_{12} - u_2 - u_3 - i_1 = 0.$$

$$\Rightarrow 10 - 6u_2 - u_3 - i_1 = 0$$

$$\Rightarrow 10 = u_1 + 6u_2 + u_3 \quad \text{--- (i)}$$

Applying Kirchhoff's loop rule to ADCA:

~~10 - u1 + u2~~

$$10 - u(i_1 - i_2) + 2(i_2 + i_3 - i_1) - i_1 = 0$$

$$10 - u_1 + u_2 + u_3 - u_1 - i_1 = 0$$

$$10 = 7i_1 - 6i_2 - u_3 \quad \dots \quad (\text{ii})$$

Adding (i) and (ii)

$$20 = 8i_1 + 0 + 0$$

$$\Rightarrow i_1 = \frac{20}{8} = \frac{10}{4} = 2.5A.$$

Applying KCL rule to BDFB:

$$5 - 2(i_2 + i_3) - 2(i_1 + i_3 - u) = 0$$

$$5 - u_2 - u_3 - u_2 - u_3 + u_1 = 0.$$

$$\Rightarrow 5 = u_2 + u_3 + u_1 - u,$$

$$\Rightarrow 5 + u_1 = u_2 + u_3.$$

$$\text{Since } u_1 = 2.5$$

$$\Rightarrow 5 + 5 = u_2 + u_3$$

$$\Rightarrow 10 = u_2 + u_3$$

$$\Rightarrow i_2 + i_3 = 2.5$$

$$\Rightarrow i_2 = 2.5 - i_3 \quad \dots \quad (\text{iii})$$

from (i) :

$$10 = i_1 + 6i_2 + 2i_3$$

Putting $i_1 = 2.5$, $i_2 = 2.5 - i_3$

$$\Rightarrow 10 = 2.5 + 6(2.5 - i_3) + 2i_3$$

$$\Rightarrow 10 = 2.5 + 15 - 6i_3 - 2i_3$$

$$\Rightarrow 8i_3 = 15$$

$$\therefore i_3 = \frac{15}{8} A.$$

$$\therefore i_2 = 2.5 - \frac{15}{8} A.$$

$$\Rightarrow \frac{20 - 15}{8} A.$$

$$\Rightarrow \frac{5}{8} A.$$

current in AB $\rightarrow i_2 = \frac{5}{8} A = 0.625 A.$

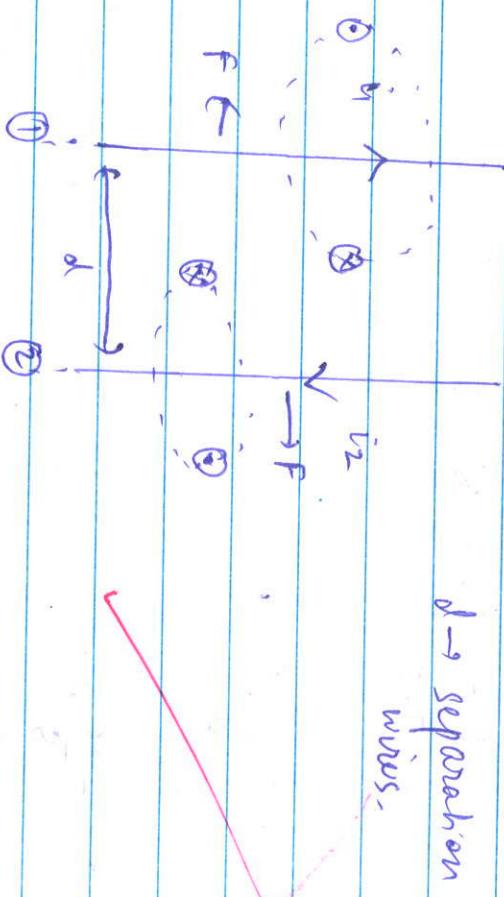
current in AC $\rightarrow i_1 = 2.5 A$

current in BC $= i_2 + i_3 = 2.5 + \frac{15}{8} = \frac{20}{8} = 2.5 A.$

(Ans)

(23)

Due to current flow in one wire, a magnetic field exists. Due to this field, another current carrying wire experiences magnetic force (IBl).



$i_1, i_2 \rightarrow$ currents in the wire

Clearly, the magnetic field due to each wire is perpendicular to the plane containing the two wires.

(P.T.O)

Field due to ① at ② :

By Ampere's circuital law :

$$\oint \vec{B}_1 \cdot d\vec{l} = \mu_0 i_1$$

Amperean loop (circle) of radius d is constructed (with wire ① as axis)
current enclosed, i_1

Clearly, magnetic field \vec{B}_1 is tangential to the loop at every point θ
 $\therefore \oint \vec{B}_1 \cdot d\vec{l} = B_1 \cdot 2\pi d.$

$$\textcircled{1} \quad \Sigma_1 \quad B_1 2\pi d = \mu_0 i_1$$

$$\Rightarrow B_1 = \mu_0 i_1$$

end

B_1 is normal to wire ②. ($\theta = 90^\circ$)

∴ magnetic force on wire ② due to ①: (on origin)

$$F_u = i_2 l B_1 \sin 0 = i_2 l B_1 \quad (\theta = 90^\circ)$$

$$\Rightarrow F_u = \mu_0 i_1 i_2 l$$

end

$$\text{if } t_{21} - \text{ force per unit length} : f_u = \frac{\mu_0}{2\pi} i_1 i_2$$

By cross-product rule, the force on wire ② is away from
wire ①.

Since magnetic field \vec{B}_2 due to ② or ①:

$$B_2 = \frac{\mu_0 i_2}{\text{end}}$$

Force on length l of ①:

$$\begin{aligned} f_{12} &= \mathbf{B}_2 \cdot \mathbf{i}_1 l B_2 \sin \theta \\ &= i_1 l B_2 \quad (\theta = 90^\circ) \\ &= \text{①} \frac{\mu_0}{\text{end}} i_1 l - l. \end{aligned}$$

If $l = 1$, force per unit length,

$$f_{12} = \frac{\mu_0 i_1 i_2}{\text{end}}$$

This force is directed away from wire ② -

$$f_{21} = -f_{12}$$

- Force per unit length on each wire,

$$f = \frac{\mu_0 i_1 i_2}{\text{end}}$$

currents in wires ① and ② are antiparallel. Thus, the force is repulsive since force on one wire is directed away from the other.

(iv)

(a) Since current leads voltage by $\frac{\pi}{2}$ on a primary capacitive circuit

$\therefore X \rightarrow$ capacitor.

(b) Capacitive reactance, $X_C = \frac{1}{\omega C}$

where $C \rightarrow$ its capacitance

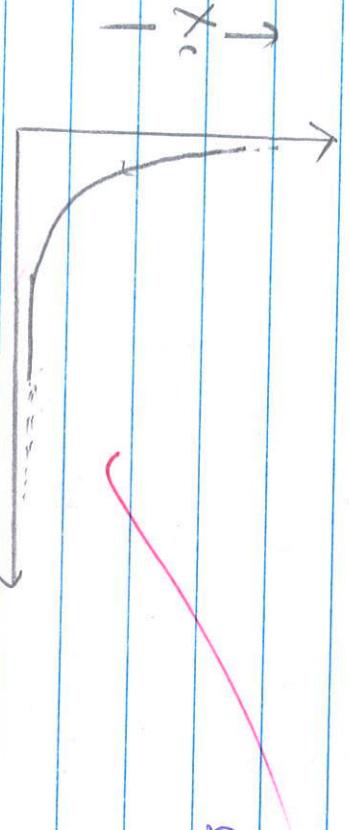
$\omega \rightarrow$ angular frequency of an input

(c)

$$\text{Since } X_C = \frac{1}{\omega C}$$

Graph is rectangular hyperbola.

$-w \rightarrow$



- (24) (d) (i) In ac circuit, capacitor is a non-dispersive element.
 - Avg power dissipation across a capacitor is zero over one cycle.

$$\text{Now, } X_C = \frac{1}{\omega C}$$

- for very high frequency ac input, capacitor offers negligible reactance to ac signal.

Also, $i = \frac{V_m \sin(\omega t + \frac{\pi}{2})}{X_C}$ is purely capacitive circuit.

- (ii) In dc circuit, capacitor is used to store electrical energy ($\frac{1}{2}CV^2$). On applying voltage, a capacitor draws charge from the source. On complete charging i.e., in steady state, there no current flows in the capacitor arm \Rightarrow Thus, it offers infinite resistance to the current in steady state.

$$(25) \quad \vec{E} = 6 - 3 \cos(1.5t) + 4 \sin(1.5 \times 10^8 t) \text{ N/C}$$

$$(a) \quad k = 1.5 \text{ rad m}^{-1}, \omega = 4.5 \times 10^8 \text{ rad s}^{-1}$$

$$\text{Wavelength, } \lambda = \frac{\text{Freq}}{k} \cdot \frac{2\pi}{\nu} = \frac{2\pi \times 2}{\frac{3}{4} \times 1.5} = \frac{1.04}{\frac{3}{4}} = \frac{4.16}{3} = 1.3866 \text{ m}$$

$$= \frac{1.3866}{12.56} = \frac{3.45}{315} = \frac{1.04}{7} = 0.149 \text{ m}$$

$$\therefore \lambda = 0.187 \text{ m.}$$

~~Ans~~

$$\text{frequency, } \nu = \frac{\omega}{2\pi} = \frac{4.5 \times 10^8 \times 7}{2\pi}.$$

$$\therefore \frac{4.5 \times 7}{2\pi} \times 10^7$$

$$\frac{4.5}{3.08}$$

$$= 7.16 \times 10^7 \text{ Hz.}$$

$$\frac{4.5}{260}$$

$$\frac{4.5}{308}$$

$$\frac{4.5}{7}$$

$$(b) F_0 = 6.3 \text{ N C}^{-1}.$$

Wl. wave,

$$F_0 = c B_0 \quad (c \rightarrow \text{speed of light in vacuum})$$

$$\Rightarrow B_0 = \frac{F_0}{c} = \frac{6.3}{3 \times 10^8} = 2.1 \times 10^{-8} \text{ T}$$

(c) \vec{E} is along \hat{c} & velocity of wave is along $-\hat{f}$.

Since $\vec{E} \times \vec{B} = \vec{J}$,

\vec{B} must be along \hat{k} .

$$\therefore \vec{B} = (2.1 \times 10^{-8} T) \cos(1.5\pi t + 4.5 \times 10^8 t) \hat{k}$$

$$\text{or } \vec{B} = (2.1 \times 10^{-8} T) [\cos(1.5 \text{ rad m}^{-1}) t + (4.5 \times 10^8 \text{ rad s}^{-1}) t] \hat{k}$$

(d)

- Bohr's first postulate: an electron in an atom can move around the nucleus in certain stable orbits without the emission of radiant energy.
- These energy-shells of an atom are called stationary states and have definite energies.

Bohr's second postulate: an electron can revolve around the nucleus only in those orbits for which the angular momentum (L) is an integral multiple of $\frac{h}{2\pi}$. Thus, the angular momentum of the revolving electron is quantized.

$$L = nh \quad \therefore v = \frac{nh}{2\pi r} \quad \text{(i)}$$

$2\pi r$

$$\Rightarrow mvn = nh$$

$2\pi r$

$m \rightarrow$ mass of electron,

~~it's radius \rightarrow r .~~

$n \rightarrow$ radius of n^{th} orbit

$v \rightarrow$ orbital speed of e^- in n^{th} orbit.

Now, the electrostatic interaction with nucleus of proton provides the necessary centripetal force to the electron.

Thus,

$$\frac{mv^2}{r} = \frac{1}{4\pi\epsilon_0} \frac{e^2}{r^2}$$

from (i)

$$\Rightarrow n = \frac{1}{4\pi\epsilon_0} \cdot \frac{m v^2}{e^2 (nr)^2 \cdot m^2 n^2}$$

$$\Rightarrow n = \frac{1}{4\pi\epsilon_0} \cdot \frac{m v^2}{e^2 (nr)^2 \cdot m^2 n^2}$$

$$\Rightarrow mv^2 = \frac{1}{4\pi\epsilon_0} \frac{e^2}{r} \quad \Rightarrow \frac{1}{r} = \frac{1}{4\pi\epsilon_0} \cdot \frac{me^2}{v^2} \cdot \frac{1}{n^2}$$

$$\Rightarrow n = \frac{1}{4\pi\epsilon_0} \frac{e^2}{m v^2} \quad \Rightarrow n = \frac{4\pi\epsilon_0}{me^2} \cdot \left(\frac{h}{2\pi r} \right)^2 \cdot n^2$$

$$\text{Area} = \frac{\pi r^2}{\text{area}}$$

$$q) \pi = \frac{\pi r^2}{\text{area}}$$

Ans

- Radius of nth orbit:

$$r_n = \frac{e_0 h^2}{\text{area}} \cdot n^2$$

$$\text{Ans}$$

where $a_0 = \frac{e_0 h^2}{\text{area}}$ is radius of first orbit (1st)

Ans

$$\therefore r_n = \frac{h^2 e_0}{\text{area}} \cdot n^2$$

(Ans)

Q. 1.0)

(b) One atomic mass unit (u) is defined as one-twelfth the mass of one ^{12}C atom.

mass of one carbon-12 atom = $1.67 \times 10^{-26} \text{ kg}$.

$$\therefore 1u = \frac{1.67 \times 10^{-26} \text{ kg}}{12} \times 10^{-26} \text{ kg} \approx 0.167 \times 10^{-27} \text{ kg}$$

$$= 1.67 \times 10^{-27} \text{ kg.}$$

(b) Deuterium $\rightarrow ^2\text{H}$.

(i) m_p

$$\text{Total mass of protons} = 1 \times 1.007825u = 1.007825u$$

$$\text{Mass of 1 neutron} = 1 \times 1.008665u = 1.008665u$$

$$\text{Total mass (neutron + proton)} = m_p + m_n = 2.016490u$$

mass of deuterium, $m(D) = 2.0164902u$.

\therefore mass deficit $= m - m(D)$

$$\Delta m = 2.016490$$

$$- 2.016490$$

~~$$0.002388$$~~

~~$$\frac{1.007825}{1.008665}$$~~

~~$$\frac{0.002388}{0.000840}$$~~

~~$$\frac{2.016490}{2.016490}$$~~

~~$$\frac{0.002388}{0.000840}$$~~

~~$$\frac{1.8630}{2.223420}$$~~

$$\text{Energy equivalent of } 1 \text{ amu} = \Delta m \times c^2$$

$$= 1.67 \times 10^{-27} \times 9 \times 10^{16} \text{ J}.$$

~~$$= 1.6 \times 10^{-19}$$~~

~~$$= 931.5 \times 10^6 \text{ eV.}$$~~

$$= 931.5 \text{ MeV.}$$

∴ Energy required to separate

a deuteron into free nucleons = $\Delta m c^2$

(Binding energy)

$$= \Delta m \times 931.5 \text{ MeV}$$

~~$$= 0.002388 \times 931.5$$~~

~~$$= 3.6 \times 10^{-13} \text{ J.}$$~~

$$= 3.6 \times 10^{-13} \text{ J.}$$

✓

$$\begin{aligned} E &= 2 \cdot 92u \times 10^6 \times 1.6 \times 10^{-19} \\ &= 3 \cdot 558 \times 10^{-13} \text{ J} \end{aligned}$$

$$\therefore 3 \cdot 56 \times 10^{-13} \text{ J}$$

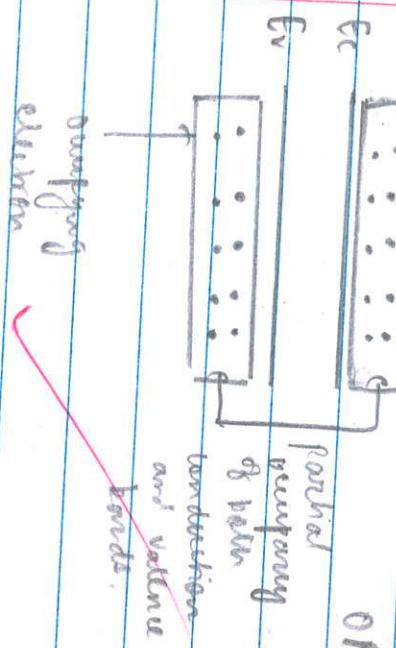
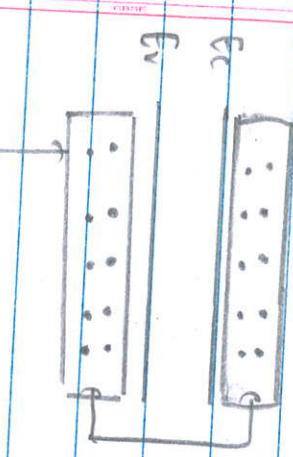
$\mu_{\text{no}} \rightarrow$ Required energy) $= 2 \cdot 22 \text{ MeV}$

$$m = 3 \cdot 56 \times 10^{-13} \text{ J}$$

(c) Energy band diagrams:

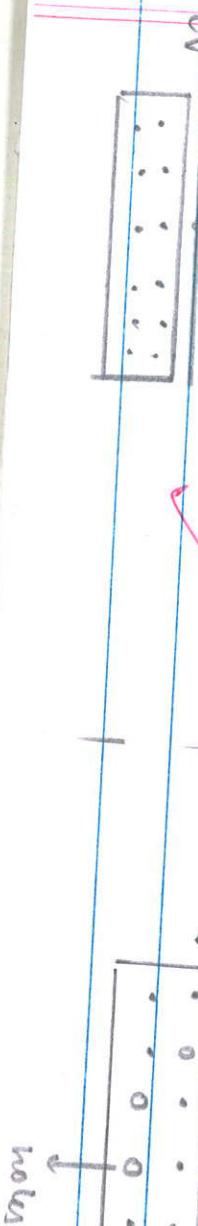
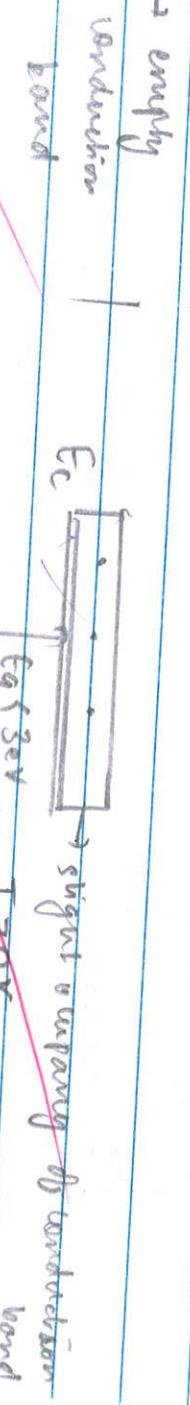
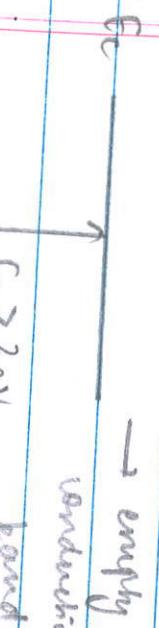
here, $E_c \rightarrow$ below $E_c \rightarrow$ conduction band, $E_v \rightarrow$ valence band

$E_g \rightarrow$ energy gap (forbidden gap)
for metals



For insulators:

For semiconductors



holes

Metals

- Either both conduction and valence bonds are partially filled or conduction and valence bonds overlap, so that band gap, $E_g = 0$.
- Metals are poor conductors of electricity, while partial occupancy of conduction band is OK when $E_g = 0$.

Eg: copper.

Insulators

- Here, band gap $E_g > 3\text{ eV}$. Electrons cannot be normally excited from valence band to conduction band, leaving vacancies in the valence band.
- No electrons in conduction band, hence there do not conduct.
- High resistivity, low conductivity.

Eg: air

Semiconductors

- Band gap, $E_g < 3\text{ eV}$. At adequate temperatures electrons excite to conduction band, leaving vacancies in the valence band.
- At 0 K , semiconductors are insulators since conduction band is empty.
- At $\oplus T > 0\text{ K}$, there conduct due to flow of electrons in conduction band and holes in valence band.
- Intermediate resistivity between metals and insulators.

Eg: silicon.

Section D

(16) (c) (D) ~~III~~

$$d = 2 \text{ mm}$$

$$d = 6 \text{ mm}$$

(ii) Accelerate along -i

$$(A) V = V_0 + \alpha t$$

$$W = \frac{\alpha}{d}$$

$$V = V_0 + Ed.$$

$$V_0 + \frac{E}{M} d$$

$$(iii) (B) \epsilon_4 > \epsilon_3 > \epsilon_2 > \epsilon_1$$

$$\frac{2\eta}{d} = \frac{n\eta}{d}$$

$$\frac{2d}{\eta} = \frac{n}{d}$$

(30)

$$(C) (D) 6$$

$$\frac{2d}{\eta} = n$$

$$V = \frac{E}{d}$$

$$\rightarrow n = \frac{2d}{\eta}$$

$$\epsilon_1 = 20$$

$$\frac{2d}{\eta} = n$$

$$n = \frac{2d}{\eta}$$

$$\epsilon_2 = 200$$

$$\epsilon_3 = 220$$

$$\frac{2d}{\eta} = n$$

$$\frac{2d}{\eta} = n$$

$$\epsilon_4 = 300$$

$$\frac{2d}{\eta} = n$$

$$\epsilon_4 > \epsilon_3$$

Section E

(CORI)

(i)

$R \rightarrow$ radius of spherical shell

$\Theta Q \rightarrow$ charge

$$\text{Let } \sigma = \frac{Q}{A} = \frac{Q}{4\pi R^2} \text{ (surface charge density).}$$

We consider a spherical gaussian surface of radius $r < R$.

charge enclosed by sphere $= 0$.

By Gauss' law

$$\text{Electric flux, } \Phi_E = \frac{\text{enclosed}}{\epsilon_0} = 0.$$

$$\frac{1}{2} \times \frac{2}{50} \times 10^{-6} \times 3 = 0$$

$$10^3 \times 10^{-9} = 0$$

$$\Phi_E = \vec{E} \cdot \vec{A}$$

$$\vec{E} = 0$$

$\therefore E = 0$ (since $\vec{E} \neq 0$, and $\vec{E} \cdot \vec{A} = 0$)

\therefore electric field, it inside the shell = 0

$$E = \frac{\sigma}{\epsilon_0}$$

(Q) Use (i) we consider a Gaussian surface with radius $r > R$.

Then electric flux, Φ_E through the surface,

$$\Phi_E = \oint \vec{E} \cdot d\vec{s}$$

$$\Rightarrow E \cdot 4\pi r^2$$



$$\vec{ds}$$

Since the electric field is normal to the closed surface.

(taken in along the area vector) at every point

$$(\therefore \theta = 90^\circ, E \cos 90^\circ = EA).$$

③ Total charge enclosed : ~~closed~~ σA .

\therefore Electric field at r from centre :

$$E_{\text{ext}}$$

By Gauss' Law,

$$E 4\pi r^2 = \frac{Q}{\epsilon_0}$$

$$\Rightarrow E = \frac{Q}{4\pi \epsilon_0 r^2}$$

radially outward !

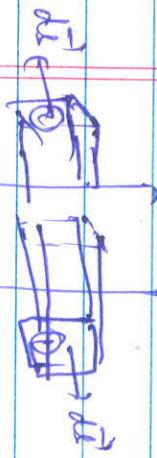
\therefore Electric field, outside $= 0$ $E_{\text{out}} = \frac{Q}{4\pi \epsilon_0 r^2}$ ($r > R$)

$$(r < R)$$

$$E_{\text{out}} = \frac{Q}{4\pi \epsilon_0 r^2}$$

31 (b) (a) For a non-conducting ~~CB~~ infinite sheet:

Surface charge density = σ .



We consider a Gaussian parallelepiped.

Since electric field is along the lateral surfaces.
Electric flux, $\oint E \cdot d\vec{l}$ through lateral surfaces = 0.

Now, E is normal to the cross-sections of the parallelepiped. let A be over sectional area.

Flux through surface ① \rightarrow $E A$ outward
And $\oint_2 \Phi_2 \rightarrow EA$ inward

$$\text{Total flux, } \oint \Phi \rightarrow \Phi_1 + \Phi_2 \\ \rightarrow 2EA$$

By Gauss' Law,

$$\Phi = \frac{q_{\text{enclosed}}}{\epsilon_0}$$

$$2EA = \frac{\sigma A}{\epsilon_0}$$

$$\therefore \sigma = \frac{\epsilon_0}{2A} \checkmark$$

Next, we consider a conducting surface, with some surface charge density σ .

① If we consider an elemental gaussian cylinder:

+  field is along the curved surface, \therefore flux through curved surface = 0

Flux through surface $\rightarrow EA$ ($\because E$ is along \vec{d})

Φ_1 , where $A \rightarrow$ area of cross section.

Net charge $\rightarrow E = 0$ zero inside a conductor.

$$\therefore \Phi_2 = 0$$

$$\therefore \text{Total flux} (\Phi) = EA. (C)$$

By Gauss' Law,

$$\Phi = \sigma \text{ enclosed}$$

(by Gaussian cylinder)

$$\Rightarrow EA = \sigma A$$

$$\therefore$$

$$\Rightarrow E = \frac{\sigma}{\epsilon_0}$$

Electric field

$$\text{inside conductor charged} \rightarrow \frac{\sigma}{\epsilon_0}$$

outside no charged non-conducting plate $\rightarrow \frac{\sigma}{2\epsilon_0}$

Clearly, the magnitude of electric field is double for the condensing plate.

2024

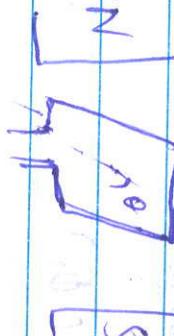
OR

(32) (b) (i) \rightarrow

Let A be the area of coil.

$w \rightarrow$ angular speed.

Let $\theta = wr$ so that $\theta = 0$ at $t = 0$.



\vec{B} (uniform magnetic field)

By Faraday's law of Electromagnetic induction,
Induced emf or $E = N \frac{d\phi_B}{dt}$

\checkmark

magnetic flux Φ_B through coil $\Rightarrow \vec{B} \cdot \vec{A} = BA$ (only way to link flux & field)

$\Rightarrow BA \text{ will change}$

$\Rightarrow BA \text{ will change}$

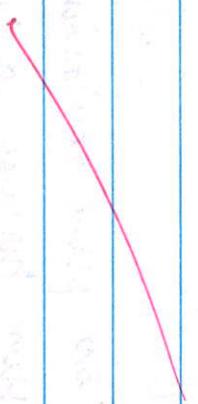
$$\therefore e = -N \frac{d}{dt} BA \text{ law}$$

$$\frac{d}{dt}$$

$$= NBA \frac{d}{dt} \Phi_B$$

$$\frac{d}{dt}$$

$$\Rightarrow NBAn \sin \omega t.$$



$$\therefore (\text{Induced}) e = NBS \sin \omega t$$

$$e = \epsilon_0 \sin \omega t$$

$$\text{Where } \epsilon_0 = NBAn$$

(constant in the given case)

(ii)

$$r_1 = 1 \text{ cm}, \quad r_2 = 100 \text{ cm}$$

$$\text{Clearly, } r_2 > r_1$$

Steady magnetic field due to current carrying loop

$$\beta = \frac{\mu_0 i R^2}{4\pi r^2}$$

$$0.2 \text{ (R}^2 \text{ m}^2\text{)}$$



Q) At what rate i flows through L_2

$$\therefore B \text{ at wire } L_2 = \frac{\mu_0 i}{2r}$$

Since $\mu_0 > r_1$, the magnetic field can be assumed to be constant along L_1 .

\rightarrow B is normal to the plane containing the loop.

Q) \because magnetic flux through $\text{loop } L_1$

$$\Phi_B = \int B \cdot dA \quad (C: \theta = 0^\circ, \Phi_B \text{ along } \vec{B})$$

$$\Rightarrow \Phi_B = \mu_0 \pi r_1^2$$

$$\therefore \Phi_B = \mu_0 \pi r_1^2 \cdot i$$

But flux linked to $\text{loop } L_2$

$$\Phi_1 = M_{12} i_2$$

where $M_{12} \rightarrow$ mutual inductance of L_1 w.r.t L_2

$$\therefore M_{12} = \mu_0 \pi r_1^2$$

We know,

$$M_2 \rightarrow M_2 \rightarrow M$$

$$\therefore M_2 = M_0 \pi r^2$$

$$2M_2$$

$$\frac{M_0}{\cancel{\pi}} M_2 = \cancel{\pi} r^2 \times 10^{-7} \cdot 0.1 \times 10^{-9}$$

$$2 \times \cancel{10^{-10}} \cdot 1.$$

$$2 \times \cancel{\pi} r^2 \times 10^{-11}$$

$$2 \times 20 \times 10^{-11} = 3.2 \times 10^{-10}$$

$$\Rightarrow 2 \times 10^{-10}$$

$$\therefore Mutual inductance = 2 \times 10^{-10} H$$

$$(P.T.O.)$$

पृष्ठा के इसका
नंतर column and

(n)

CBSE

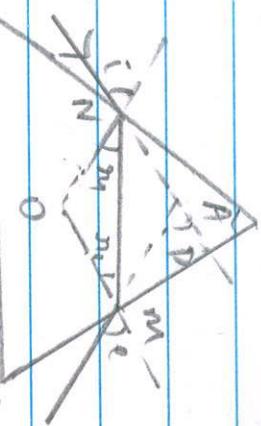
(33)(a) c)

A

\rightarrow angle of incidence (from page 1)

$i \rightarrow$ angle of incidence

$n_1 \rightarrow$ angle of refraction at 1st interface



$D_1 \rightarrow$ angle of emergence

$D \rightarrow$ angle of deviation

$n_1, n_2 \rightarrow$ refractive index of the surfaces

By geometry,

$$D = i - r_1 + e - r_2 \quad (\text{constant angle})$$

$$D = i + e - (r_1 + r_2)$$

In quadrilateral ANOM

$$\textcircled{D} \quad \angle A + \angle ANO + \angle NOM + \angle NOM = 360^\circ$$

$$\textcircled{D} \rightarrow \angle A + 180^\circ \rightarrow \angle NOM = 360^\circ$$

$$\Rightarrow \angle A = 180^\circ - \angle NOM$$

In $\triangle NOM$,

$$n_1 + n_2 + \angle NOM = 180^\circ$$

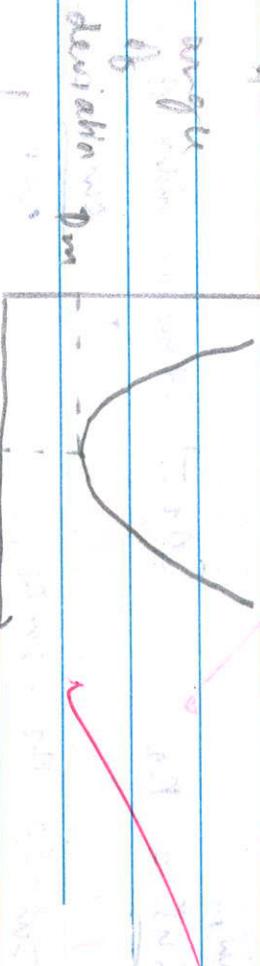
$$n_1 + n_2 = 180^\circ - \angle NOM$$

$$f = n_1 + n_2.$$

$$\Rightarrow D^2 = \bar{x}^2 - A$$

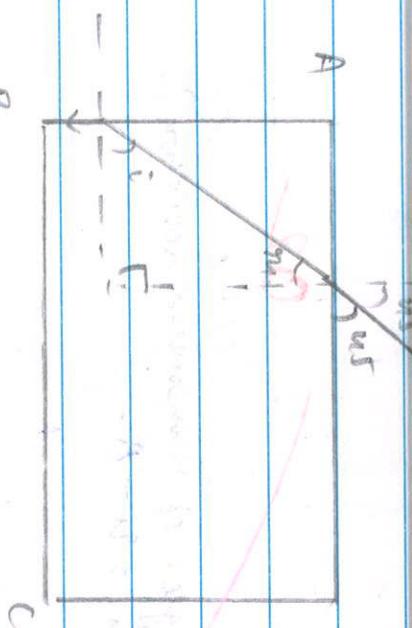
when $D^2 = D_m$ change of minimum deviation
size and $D_m = \bar{x} - A$.

$$D \uparrow$$



large D inversion \rightarrow

(i)



A

D

$n_2 = \frac{3}{2}$ (Grenz)

By Snell's law,

$$\frac{\sin i}{\sin r_2} = n_2$$

$$\therefore \sin i = n_2 \cdot \sin r_2$$

$$\Rightarrow \sin r_2 = \frac{\sin i}{n_2}$$

$$\frac{1}{\sqrt{2}n_2}$$

$$\Rightarrow \sin r_2 = \frac{1}{\sqrt{2}n_2}$$

$$\therefore \sin r_2 = \frac{1}{\sqrt{2}}$$

$$\therefore \cos r_2 = \frac{1}{\sqrt{2}}$$

in liquid

By geometry,

$$i + r_2 = 90^\circ$$

$$\Rightarrow \sin i = \sin(90^\circ - r_2) = \sqrt{1 - \frac{1}{n_2^2}}$$

$$\Rightarrow \sin i = \sqrt{1 - \frac{1}{n_2^2}} = \frac{1}{\sqrt{2}}$$

$$\therefore \cos r_2 = \frac{1}{\sqrt{2}}$$

✓